

Current Transducer HAIS 50..400-P and HAIS 50..100-TP

For the electronic measurement of currents: DC, AC, pulsed..., with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).



R,

C

V_C







All data are given with a $\mathbf{R}_1 = 10 \text{ k}\Omega$

≥ 200

≥ 2

< 10

< 1

5

22

 $k\Omega$

 $k\Omega$

Ω

μF

mΑ

$I_{PN} = 50 ... 400 A$



Electrical data

Load resistance

Capacitive loading

Output internal resistance

Current consumption @ $V_c = 5 \text{ V}$

Supply voltage (± 5 %)

Primary nominal current rms I _{PN} (A)	Primary current measuring range I _{PM} (A)	Туре		RoHS date	
50	± 150	HAIS 50-P, HAIS	50-TP 1)	45231	, 46272
100	± 300	HAIS 100-P, HAI	S 100-TP 1)	45231	, 46012
150	± 450	HAIS 150-P		46172	
200	± 600	HAIS 200-P		45231	
400	± 600	HAIS 400-P		47096	
V _{OUT} Output vol	tage (Analog) @ I _P				I_P/I_{PN})V
	I _P =	: 0	V _{REF} ±	0.025	V
V _{REF} Reference	voltage 2) - Output v	oltage	2.5 ± 0		V
	V _{DEE} Output in	mpedance	typ. 200		Ω

V_{REF} Load impedance

Accuracy - Dynamic performance data

Х	Accuracy 3 @ I _{DN} , T _A = 25°C	≤±1	% of I _{PN}
	Linearity error 0 3 x I _{PN}	≤±0.5	% of I _{PN}
	Temperature coefficient of $\mathbf{V}_{OF} \otimes \mathbf{I}_{P} = 0$	≤ ± 0.3	mV/K
	0 <u>2</u> ·		
	Temperature coefficient of V _{REF}	≤ ± 0.01	%/K
TCV _{OUT} /V _{REF}	Temperature coefficient of $\mathbf{V}_{OUT}/\mathbf{V}_{REF} \otimes \mathbf{I}_{P} = 0$	$\leq \pm 0.2$	mV/K
TCV	Temperature coefficient of V _{OUT}	\leq ± 0.05% of	reading/K
V _{OM}	Magnetic offset voltage $@$ $I_P = 0$,		
0	after an overload of 3 x I _{PN DC} HAIS 50-(T)P	$< \pm 0.5$	% of I_{PN}
	HAIS 100-(T)P400-P	$< \pm 0.4$	% of I _{PN}
t _{ra}	Reaction time @ 10 % of I _{PN}	< 3	μs
t,	Response time to 90 % of I _{PN} step	< 5	μs
di/dt	di/dt accurately followed	> 100	A/µs
\mathbf{V}_{no}	Output voltage noise (DC10 kHz)	< 15	mVpp
	(DC 1 MHz)	< 40	mVpp
BW	Frequency bandwidth (- 3 dB) 4)	DC 50	kHz

Notes: 1)-TP version is equipped with a primary bus bar.

Features

- Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation test voltage 2500V
- · Low power consumption
- Single power supply +5V
- · Fixed offset & gain
- Bus bar version available for 50A and 100A ratings.
- Isolated plastic case recognized according to UL94-V0.

Advantages

- · Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.
- V_{REF}. IN/OUT

Applications

- AC variable speed drives
- Static converters for DC motor drives
- · Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

Application domain

Industrial.

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LEM reserves the right to carry out modifications on its transducers, in order to improve them, without prior notice.

²⁾It is possible to overdrive V_{REF} with an external reference voltage between 2 - 2.8 V providing its ability to sink or source approximately 2.5 mA.

³⁾Excluding offset and hysteresis.

⁴⁾Small signal only to avoid excessive heatings of the magnetic core.



Current Transducer HAIS 50..400-P and HAIS 50..100-TP

	General data		
T ,	Ambient operating temperature	- 40 + 85	°C
T _s	Ambient storage temperature	- 40 + 85	°C
m	Mass (in brackets : TP version)	20 (30)	g
	Standards	EN 50178: 1997	

Isolation characteristics

V _b	Rated isolation voltage rms with IEC 61010-1 standards and following conditions - Single insulation - Over voltage category III - Pollution degree 2	300	V rms
V _b	- Heterogeneous field Rated isolation voltage rms with EN 50178 standards and following conditions - Reinforced insulation - Over voltage category III - Pollution degree 2	600	V rms
\mathbf{V}_{d}	- Heterogeneous field Rms voltage for AC isolation test, 50 Hz, 1 min Partial discharge extinction voltage rms @ 10pC	2.5	kV
- e	HAIS 50400-P	> 1	kV
	HAIS 50100-TP	> 1.4	kV
$\hat{\mathbf{V}}_{w}$	Impulse withstand voltage 1.2/50 µs	8	kV

HAIS 50..400-P > 1 KV HAIS 50..100-TP > 1.4 kV $\hat{\mathbf{V}}_{\mathbf{w}}$ Impulse withstand voltage 1.2/50 μ s 8 kV dCp Creepage distance > 8 mm dCI Clearance distance > 8 mm CTI Comparative tracking index (Group I) > 600

If insulated cable is used for the primary circuit, the voltage category could be improved with the following table:

Cable insulation (primary)

Category

 HAR 03
 450V CAT III

 HAR 05
 550V CAT III

 HAR 07
 650V CAT III

Safety



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



Caution, risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

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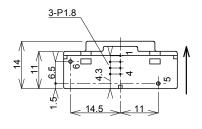


Dimensions HAIS 50..400-P and HAIS 50..100-TP (in mm. 1 mm = 0.0394 inch)

HAIS 50..400-P

Front view 33 15 2-D1.0 4-0.25x0.45

Bottom view



Terminal Pin Identification

- 1...+5V
- 2...0V
- 3...OUTPUT
- 4...Vref. (IN/OUT)
- 5...Core Earth (*)
- 6...NC.

Recommended PCB hole

Pin 1-4: 0.7 ±0.1mm Pin 5-6: 1.5 ±0.1mm

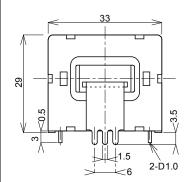
Primary bus bar : 2.3 \pm 0.1mm

General tolerance: ±0.2mm

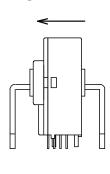
Unit: mm

HAIS 50..100-TP

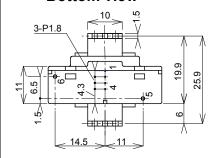
Front view



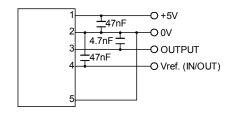
Right view



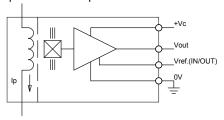
Bottom view



Required Connection Circuit



Operation Principle



^(*) should be connected to 0V of Power Supply for better dv/dt immunity. Arrow indicates positive current direction.

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